

# **isc Silicon NPN Power Transistor**

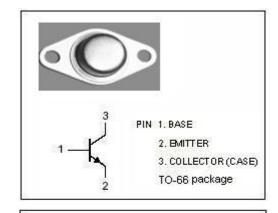
**BUX59** 

### **DESCRIPTION**

- Low Saturation Voltage
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

# **APPLICATIONS**

· Designed for use in high frequency and efficiency converters, switching regulators and motor control

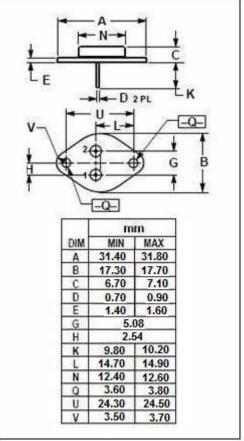


### ABSOLUTE MAXIMUM RATINGS( $T_a=25^{\circ}$ C)

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|---|--|---------|------------------------|--|--|--|
| SYMBOL                                  | PARAMETER  | VALUE   | UNIT                   |  |  |  |
| V <sub>CBO</sub>                        | Collector-Base Voltage                           | 120     | V                      |  |  |  |
| V <sub>CEO</sub>                        | Collector-Emitter Voltage                        | 90      | V                      |  |  |  |
| V <sub>EBO</sub>                        | Emitter-Base Voltage                             |         | V                      |  |  |  |
| Ic                                      | Collector Current-Continuous                     | 8       | Α                      |  |  |  |
| Pc                                      | Collector Power Dissipation@T <sub>C</sub> =25°C | 70      | W                      |  |  |  |
| TJ                                      | Junction Temperature                             | 200     | $^{\circ}$             |  |  |  |
| T <sub>stg</sub>                        | Storage Temperature                              | -65~200 | $^{\circ}\!\mathbb{C}$ |  |  |  |

#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                           | MAX | UNIT |
|---------------------|-------------------------------------|-----|------|
| R <sub>th j-c</sub> | Thermal Resistance,Junction to Case | 5.0 | °C/W |





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**BUX59** 

#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

| SYMBOL                | PARAMETER                            | CONDITIONS                                 | MIN | MAX | UNIT |
|-----------------------|--------------------------------------|--|-----|-----|------|
| V <sub>CEO(SUS)</sub> | Collector-Emitter Sustaining Voltage | I <sub>C</sub> =50mA ; I <sub>B</sub> =0   | 90  |     | V    |
| V <sub>CE(sat)</sub>  | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 8A; I <sub>B</sub> = 0.8A |     | 1.5 | V    |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 8A; I <sub>B</sub> = 0.8A |     | 2.0 | V    |
| I <sub>CEO</sub>      | Collector Cutoff Current             | V <sub>CE</sub> = 90V; I <sub>B</sub> =0   |     | 2   | mA   |
| Ісво                  | Collector Cutoff Current             | V <sub>CB</sub> = 120V, I <sub>E</sub> =0  |     | 1.0 | mA   |
| I <sub>EBO</sub>      | Emitter Cutoff Current               | V <sub>EB</sub> = 6V; I <sub>C</sub> =0    |     | 0.5 | mA   |
| h <sub>FE-1</sub>     | DC Current Gain                      | Ic= 4A; VcE= 5V                            | 20  | 60  |      |



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